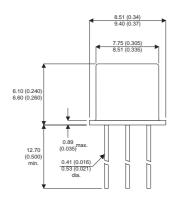
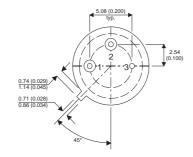


### **MECHANICAL DATA**

Dimensions in mm (inches)





### TO39 PACKAGE (TO-205AD)

Pin 1 = Emitter

Pin 2 = Base

Pin 3 = Collector

# **HIGH VOLTAGE NPN TRANSISTORS**

### **FEATURES**

- DUAL SILICON PLANAR EPITAXIAL NPN **TRANSISTOR**
- HIGH VOLTAGE

## **APPLICATIONS:**

These devices are particularly suited as drivers in high-voltage low current inverters, switching and series regulators.

<b>ABSOLUTE MAXIMUM RATINGS</b> (T <sub>case</sub> = 25°C unless otherwise stated)		2N3439	2N3440	
$\overline{V_{CBO}}$	Collector – Base Voltage (I <sub>E</sub> = 0)	450V	300V	
$V_{CEO}$	Collector – Emitter Voltage (I <sub>B</sub> = 0)	350V	250V	
$V_{EBO}$	Emitter – Base Voltage (I <sub>C</sub> = 0)	7V		
I <sub>C</sub>	Collector Current	1A		
$I_{B}$	Base Current	0.5A		
$P_{tot}$	Total Power Dissipation at T <sub>case</sub> ≤ 25°C	5W		
	T <sub>amb</sub> ≤ 50°C	1\	W	
T <sub>stg</sub>	Storage Temperature	–65 to 200°C		
T <sub>j</sub>	Junction Temperature	200°C		

Semelab PIc reserves the right to change test conditions, parameter limits and package dimensions without notice. Information furnished by Semelab is believed to be both accurate and reliable at the time of going to press. However Semelab assumes no responsibility for any errors or omissions discovered in its use. Semelab encourages customers to verify that datasheets are current before placing orders.

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2N3439 2N3440

## **ELECTRICAL CHARACTERISTICS** (T<sub>case</sub> = 25°C unless otherwise stated)

Parameter		Test Conditions	Min.	Тур.	Max.	Unit
V <sub>CEO(sus)*</sub>	Collector – Emitter Sustaining Voltage	I <sub>C</sub> = 50mA <b>2N3439</b>	350			V
	$(I_B = 0)$	I <sub>C</sub> = 50mA <b>2N3440</b>	250			1
I <sub>CEO</sub>	Collector Cut-off Current	V <sub>CE</sub> = 300V <b>2N3439</b>			20	
	$(I_B = 0)$	V <sub>CE</sub> = 200V <b>2N3440</b>			50	μΑ
I <sub>CEX</sub>	Collector Cut-off Current	V <sub>CE</sub> = 450V <b>2N3439</b>			500	μΑ
	$(V_{BE} = -1.5V)$	V <sub>CE</sub> = 300V <b>2N3440</b>			500	
I <sub>CBO</sub>	Collector – Base Cut-off Current	V <sub>CB</sub> = 350V <b>2N3439</b>			20	μΑ
	$(I_E = 0)$	V <sub>CB</sub> = 250V <b>2N3440</b>			20	
I <sub>EBO</sub>	Emitter Cut-off Current (I <sub>C</sub> = 0)	V <sub>EB</sub> = 6V			20	μA
V <sub>CE(sat)*</sub>	Collector – Emitter Saturation Voltage	$I_C = 50 \text{mA}$ $I_B = 4 \text{mA}$			0.5	V
V <sub>BE(sat)*</sub>	Base – Emitter Saturation Voltage	$I_C = 50 \text{mA}$ $I_B = 4 \text{mA}$			1.3	V
h <sub>FE*</sub>	DC Current Gain	I <sub>C</sub> = 20mA	40		160	
		V <sub>CE</sub> = 10V	40		100	
		I <sub>C</sub> = 2mA <b>2N3439 only</b>	30			
		V <sub>CE</sub> = 10V	30			

<sup>\*</sup> Pulse test  $t_p=300\mu s$  ,  $\delta \leq 2\%$ 

## **DYNAMIC CHARACTERISTICS** (T<sub>case</sub> = 25°C unless otherwise stated)

Parameter		Test Conditions			Min.	Тур.	Max.	Unit
f <sub>T</sub>	Transition Frequency	$I_C = 10mA$	$V_{CE} = 10V$	f = 5MHz	15			MHz
C <sub>ob</sub>	Output Capacitance	V <sub>CB</sub> = 10V		f = 1MHz			10	pF
h <sub>fe</sub>	Small Signal Current Gain	$I_C = 5mA$	V <sub>CE</sub> = 10V	f = 1kHz	25			_

#### THERMAL DATA

	Parameter	Min.	Тур.	Max.	Unit
$R_{\theta JA}$	Thermal Resistance Junction to Ambient			175	°C/W
$R_{\theta JC}$	Thermal Resistance Junction to Case			35	°C/W

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